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APPLICATION N	10.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO	
10/689,779		10/21/2003	Peter J. Hopper	100-23500 (P05712)	4526	
33402	7590	02/24/2004		EXAMINER		
LAW OFFICES OF MARK C. PICKERING P.O. BOX 300				STEIN, STEPHEN J		
	MA, CA	94953		ART UNIT	PAPER NUMBER	
				1775		
				DATE MAILED: 02/24/2004		

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	1				
	10/689,779	HOPPER ET AL.					
Office Action Summary	Examiner	Art Unit					
	Stephen J Stein	1775					
The MAILING DATE of this communication ap		vith the correspondence address					
Period for Reply							
A SHORTENED STATUTORY PERIOD FOR REPI THE MAILING DATE OF THIS COMMUNICATION  - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a report of the period for reply is specified above, the maximum statutory period.  - Failure to reply within the set or extended period for reply will, by stature to reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).  Status	. 136(a). In no event, however, may a ply within the statutory minimum of this will apply and will expire SIX (6) MOI to cause the application to become A	reply be timely filed  rty (30) days will be considered timely.  NTHS from the mailing date of this communication	on.				
1)☐ Responsive to communication(s) filed on 2a)☐ This action is <b>FINAL</b> . 2b)☒ Thi							
3) Since this application is in condition for allowa	s action is non-final.						
closed in accordance with the practice under	Fy narte Ouavle, 1935 C F	ters, prosecution as to the merits i	S				
	Ex parto Quayro, 1000 O.E	7. 11, 400 O.G. 213.					
Disposition of Claims							
4) Claim(s) 1-19 is/are pending in the application.							
4a) Of the above claim(s) is/are withdrawn from consideration.							
5) Claim(s) is/are allowed.							
6)⊠ Claim(s) <u>1-9 and 17-19</u> is/are rejected.							
7)⊠ Claim(s) <u>10-16 and 20</u> is/are objected to. 8)□ Claim(s) are subject to restriction and/o	or election requirement						
	or election requirement.						
Application Papers							
9) The specification is objected to by the Examin							
10)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.							
Applicant may not request that any objection to the							
Replacement drawing sheet(s) including the correct	tion is required if the drawing	(s) is objected to. See 37 CFR 1.121(	d).				
11)☐ The oath or declaration is objected to by the E	xaminer. Note the attached	d Office Action or form PTO-152.					
Priority under 35 U.S.C. § 119		V					
12) Acknowledgment is made of a claim for foreigr a) All b) Some * c) None of:		119(a)-(d) or (f).					
1. Certified copies of the priority document		•					
2. Copies of the partition applies of the partition							
<ol> <li>Copies of the certified copies of the prio application from the International Burea</li> </ol>		received in this National Stage					
* See the attached detailed Office action for a list		received					
Table 2 Decision Cities delicities a list	or the contined copies flot	receiveu.					
Attachment(s)							
1) Notice of References Cited (PTO-892)	4) Interview S	ummary (PTO-413)					
<ul> <li>2) Notice of Draftsperson's Patent Drawing Review (PTO-948)</li> <li>3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)</li> </ul>		)/Mail Date formal Patent Application (PTO-152)					
Paper No(s)/Mail Date	6)  Other:						

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### **DETAILED ACTION**

## Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (a) the invention was known or used by others in this country, or patented or described in a printed publication in this or a foreign country, before the invention thereof by the applicant for a patent.
- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 2. Claims 1 and 17 are rejected under 35 U.S.C. 102(b) as being anticipated by US 5,562,781 (Ingram et al.).

Ingram teaches a photodiode of alternating N type and P type semiconductor films (See abstract and Figure 4).

3. Claims 1-9 and 17-19 are rejected under 35 U.S.C. 102(e) as being anticipated by US 6,464,318 (Hopper et al.).

Hopper teaches an imager cell comprising a silicon germanium n-type semiconductor layer (layer 212), a single crystal silicon p-type layer (layer 214), a p-type silicon germanium layer (layer 216), and a p-type single crystal silicon layer (layer 218) on the p-type silicon germanium layer (See figures 3 and 4 and col. 4-6).

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## Allowable Subject Matter

4. Claims 10-16 and 20 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

5. The following is a statement of reasons for the indication of allowable subject matter:

While the prior art of record teaches an imager cell comprising a silicon germanium ntype semiconductor layer, a single crystal silicon p-type layer, a p-type silicon germanium layer,
and a p-type single crystal silicon layer on the p-type silicon germanium layer, the prior art fails
to teach or suggest that the fourth region has a greater dopant concentration than the second
region of semiconductor material. The prior art or record further fails to teach or suggest that the
imager further comprises a fifth region of semiconductor material located on the fourth region of
semiconductor material, the fifth region of semiconductor material having the first conductivity
type; a sixth region of semiconductor material located on the fifth region of semiconductor
material, the fifth region of semiconductor material having the second conductivity type; and a
seventh region of semiconductor material located on the sixth region of semiconductor material,
the seventh region of semiconductor material including silicon and germanium and having the
second conductivity type.

#### Conclusion

6. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Stephen Stein whose telephone number is 572-272-1544. The examiner can normally be reached on Monday through Friday from 8:30 a.m. to 5:00 p.m. If the

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attempts to reach the examiner are unsuccessful, the examiner's supervisor, Deborah Jones can be reached by dialing 572-272-1535. The official fax number is 703-872-9306.

February 17, 2004

Stephen J. Stein

**Primary Examiner** 

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